

# Ye Wu

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/4511517/publications.pdf>

Version: 2024-02-01

22  
papers

5,126  
citations

331538

21  
h-index

677027

22  
g-index

22  
all docs

22  
docs citations

22  
times ranked

5941  
citing authors

#	ARTICLE	IF	CITATIONS
1	A Universal Ternary Solvent Ink Strategy toward Efficient Inkjet-Printed Perovskite Quantum Dot Light-Emitting Diodes. <i>Advanced Materials</i> , 2022, 34, e2107798.	11.1	109
2	Lead-Free Halide Double Perovskites: Structure, Luminescence, and Applications. <i>Small Structures</i> , 2021, 2, 2000071.	6.9	71
3	Mn <sup>2+</sup> induced significant improvement and robust stability of radioluminescence in Cs <sub>3</sub> Cu <sub>2</sub> I <sub>5</sub> for high-performance nuclear battery. <i>Nature Communications</i> , 2021, 12, 3879.	5.8	76
4	Efficient, Stable, and Tunable Cold/Warm White Light from Lead-Free Halide Double Perovskites Cs <sub>2</sub> ZrI <sub>4</sub> TeCl <sub>6</sub> . <i>Advanced Optical Materials</i> , 2021, 9, 2100815.	3.6	30
5	Interfacial Tunneling Effect Enhanced CsPbBr <sub>3</sub> Photodetectors Featuring High Detectivity and Stability. <i>Advanced Functional Materials</i> , 2019, 29, 1904461.	7.8	70
6	Highly Luminescent and Stable Halide Perovskite Nanocrystals. <i>ACS Energy Letters</i> , 2019, 4, 673-681.	8.8	129
7	CsPbBr <sub>3</sub> Quantum Dots 2.0: Benzenesulfonic Acid Equivalent Ligand Awakens Complete Purification. <i>Advanced Materials</i> , 2019, 31, e1900767.	11.1	329
8	Surface Halogen Compensation for Robust Performance Enhancements of CsPbX <sub>3</sub> Perovskite Quantum Dots. <i>Advanced Optical Materials</i> , 2019, 7, 1900276.	3.6	138
9	Origin of green luminescence in carbon quantum dots: specific emission bands originate from oxidized carbon groups. <i>New Journal of Chemistry</i> , 2018, 42, 4603-4611.	1.4	58
10	Heterogeneous Nucleation toward Polar Solvent-Free, Fast, and One-Pot Synthesis of Highly Uniform Perovskite Quantum Dots for Wider Color Gamut Display. <i>Advanced Materials Interfaces</i> , 2018, 5, 1800010.	1.9	49
11	Perovskite photodetectors with both visible-infrared dual-mode response and super-narrowband characteristics towards photo-communication encryption application. <i>Nanoscale</i> , 2018, 10, 359-365.	2.8	32
12	Space-Confining Growth of CsPbBr <sub>3</sub> Film Achieving Photodetectors with High Performance in All Figures of Merit. <i>Advanced Functional Materials</i> , 2018, 28, 1804394.	7.8	108
13	In Situ Passivation of PbBr <sub>6</sub> <sup>4-</sup> Octahedra toward Blue Luminescent CsPbBr <sub>3</sub> Nanoplatelets with Near 100% Absolute Quantum Yield. <i>ACS Energy Letters</i> , 2018, 3, 2030-2037.	8.8	402
14	All Inorganic Halide Perovskites Nanosystem: Synthesis, Structural Features, Optical Properties and Optoelectronic Applications. <i>Small</i> , 2017, 13, 1603996.	5.2	537
15	Constructing Fast Carrier Tracks into Flexible Perovskite Photodetectors To Greatly Improve Responsivity. <i>ACS Nano</i> , 2017, 11, 2015-2023.	7.3	274
16	Simple and Fast Patterning Process by Laser Direct Writing for Perovskite Quantum Dots. <i>Advanced Materials Technologies</i> , 2017, 2, 1700132.	3.0	55
17	Highly stable and flexible photodetector arrays based on low dimensional CsPbBr <sub>3</sub> microcrystals and on-paper pencil-drawn electrodes. <i>Journal of Materials Chemistry C</i> , 2017, 5, 7441-7445.	2.7	51
18	Capping CsPbBr <sub>3</sub> with ZnO to improve performance and stability of perovskite memristors. <i>Nano Research</i> , 2017, 10, 1584-1594.	5.8	134

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19	Healing All-inorganic Perovskite Films via Recyclable Dissolution-Recrystallization for Compact and Smooth Carrier Channels of Optoelectronic Devices with High Stability. <i>Advanced Functional Materials</i> , 2016, 26, 5903-5912.	7.8	296
20	CuO/ZnO memristors via oxygen or metal migration controlled by electrodes. <i>AIP Advances</i> , 2016, 6, .	0.6	14
21	CsPbX <sub>3</sub> Quantum Dots for Lighting and Displays: Room-Temperature Synthesis, Photoluminescence Superiorities, Underlying Origins and White Light-Emitting Diodes. <i>Advanced Functional Materials</i> , 2016, 26, 2435-2445.	7.8	2,055
22	Amorphous ZnO based resistive random access memory. <i>RSC Advances</i> , 2016, 6, 17867-17872.	1.7	109